



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

35 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<21m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@12A<24m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

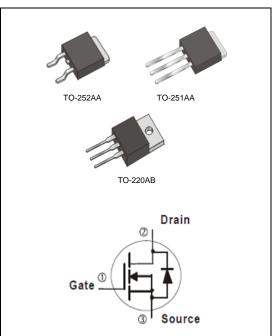
• Case: TO-251AA,TO-252AA,TO-220AB Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams

• TO-252AA Approx. Weight: 0.0105 ounces, 0.297grams

• TO-220AB Approx. Weight: 0.067 ounces, 2 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}	60			V
Gate-Source Voltage		V_{GS}	<u>+</u> 20			
Continuous Drain Current	T _C =25°C		35			A
	T _C =100°C	l _D	22			
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	140			
Power Dissipation	T _C =25°C	PD	63	104	63	W
	T _C =100°C		25	42	25	
Continuous Drain Current	T _A =25°C		4.7			А
	T _A =70°C	l _D	3.8			
Power Dissipation	T _A =25°C	_	1.1	2.0	1.1	W
Power Dissipation	T _A =70°C	Pb	0.7	1.3	0.7	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	42			mJ
Operating Junction and		T _J ,T _{STG}		°C		
Storage Temperature Range			-55~150			
Typical Thermal Resistance (Note 4,5)						
- Junction to Case		$R_{ hetaJC}$	2	1.2	2	°C/W
- Junction to Ambient		$R_{ hetaJA}$	110	62	110	

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1	1.73	2.5	
Drain Course On State Besisters	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	17	21	mΩ
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =12A	-	20	24	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Q_{g}	V _{DS} =30V, I _D =15A, V _{GS} =10V ^(Note 1,2)	-	28	-	nC
Gate-Source Charge	Q_gs		-	3.5	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V	-	6.5	-	
Input Capacitance	Ciss	201/ 1/ 01/	-	1680	-	pF
Output Capacitance	Coss	V_{DS} =20V, V_{GS} =0V, I_{S} =1,0MHZ	-	115	-	
Reverse Transfer Capacitance	Crss	I=1.UIVITZ	-	85	-	
Turn-On Delay Time	td _(on)		-	7.2	-	
Turn-On Rise Time	$V_{DD}=30V, I_{D}=1A,$		-	38	-	
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_G=6\Omega$ (Note 1,2)	-	34	-	ns
Turn-Off Fall Time	t _f		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı		-	-	35	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.67	1	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =29A, V_{DD} =25V, V_{GS} =10V, R_{G} =25ohm, Starting T_{J} =25 $^{\circ}$ C
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

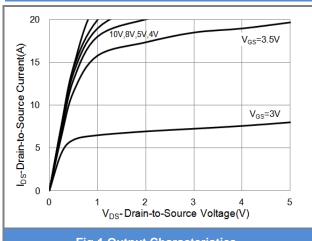


Fig.1 Output Characteristics

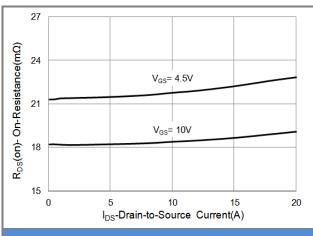


Fig.3 On-Resistance vs. Drain Current

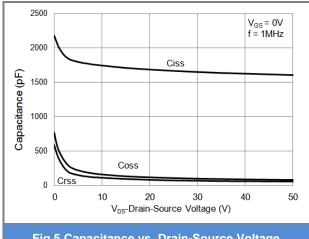
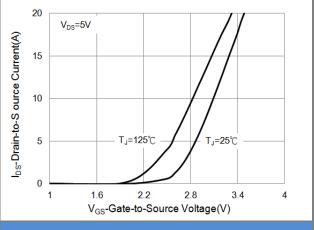


Fig.5 Capacitance vs. Drain-Source Voltage





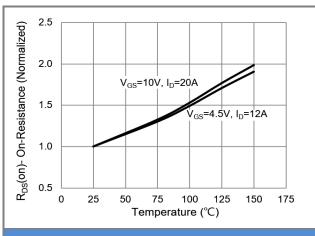


Fig.4 On-Resistance vs. Junction temperature

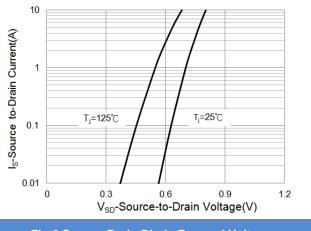


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

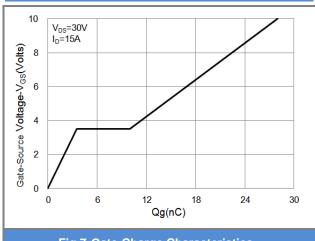


Fig.7 Gate-Charge Characteristics

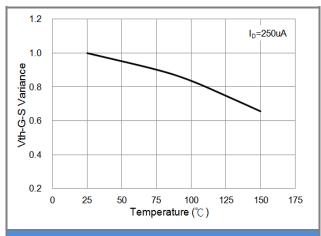


Fig.9 Threshold Voltage Variation with Temperature

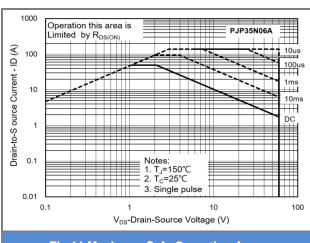


Fig.11 Maximum Safe Operating Area

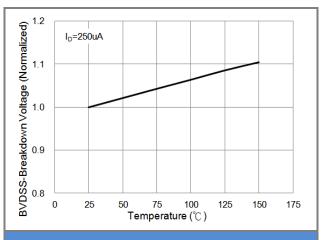


Fig.8 Breakdown Voltage Variation vs. Temperature

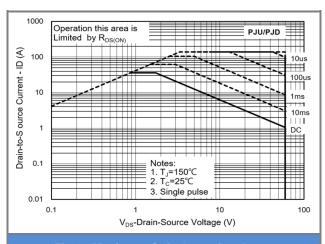


Fig.10 Maximum Safe Operating Area





TYPICAL CHARACTERISTIC CURVES

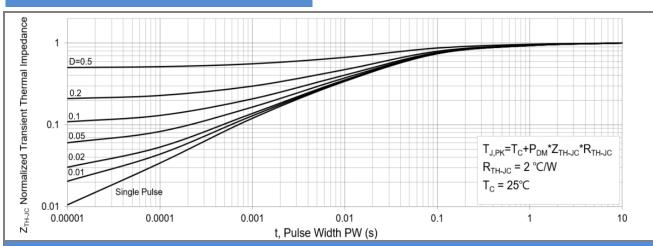


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

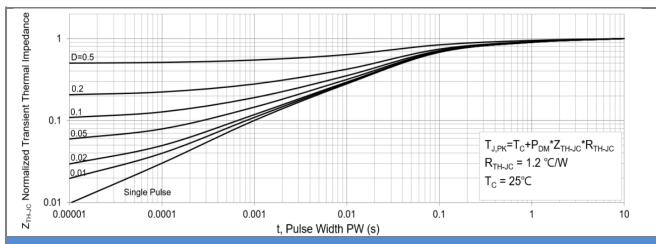
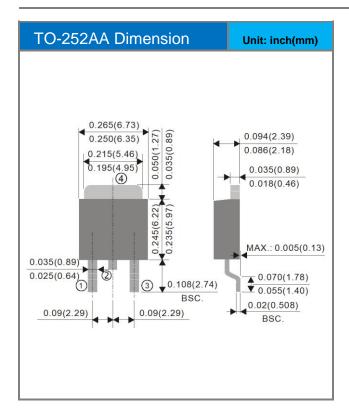


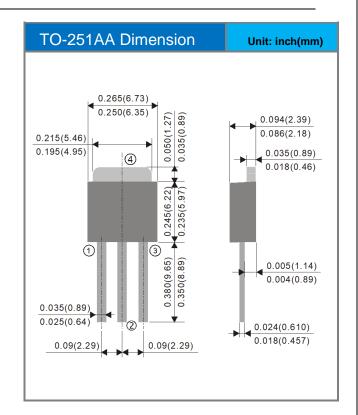
Fig.14 PJP35N06A Normalized Transient Thermal Impedance vs. Pulse Width

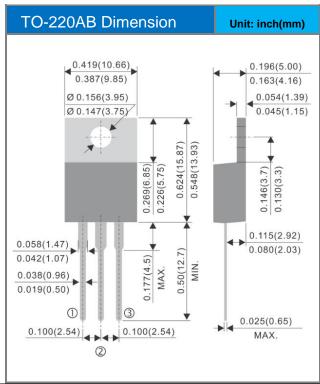




Packaging Information







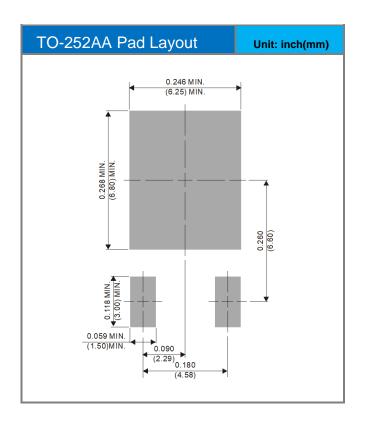




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU35N06A_T0_00001	TO-251AA	80pcs / Tube	U35N06A	Halogen free
PJD35N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D35N06A	Halogen free
PJP35N06A_T0_00001	TO-220AB	50pcs / Tube	P35N06A	Halogen free

Mounting Pad Layout







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